

## SE80PWB, SE80PWD, SE80PWG, SE80PWJ

Vishay General Semiconductor

COMPLIANT

HALOGEN

**FREE** 

## **Surface-Mount ESD Capability Rectifier**





PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	8 A				
$V_{RRM}$	100 V, 200 V, 400 V, 600 V				
I <sub>FSM</sub>	110 A				
V <sub>F</sub> at I <sub>F</sub> = 8 A (T <sub>A</sub> = 125 °C)	0.92 V				
T <sub>J</sub> max.	175 °C				
Package	SlimDPAK (TO-252AE)				
Circuit configuration	Single				

#### **FEATURES**

- Very low profile typical height of 1.3 mm
- · Ideal for automated placement
- Oxide planar chip junction
- Low forward voltage drop
- ESD capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
  - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

#### TYPICAL APPLICATIONS

General purpose, power line polarity protection, in both industry and automotive applications.

#### **MECHANICAL DATA**

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	SE80PWB	SE80PWD	SE80PWG	SE80PWJ	UNIT
Device marking code		SE80PWB	SE80PWD	SE80PWG	SE80PWJ	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	100	200	400	600	V
Maximum average forward rectified current (Fig. 1)	I <sub>F(AV)</sub> (1)	8.0				A
i waximum average forward rectilled current (Fig. 1)	I <sub>F(AV)</sub> (2)	3.5				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	110			А	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-40 to +175				°C

#### **Notes**

(1) With infinite heatsink

(2) Free air, mounted on recommended copper pad area



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Maximum Instantaneous forward voltage	I <sub>F</sub> = 4.0 A	- T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.93	-	V	
	I <sub>F</sub> = 8.0 A			1.10	1.12		
	I <sub>F</sub> = 4.0 A	T <sub>A</sub> = 125 °C		0.82	-		
	I <sub>F</sub> = 8.0 A			0.92	1.07		
Reverse current	Rated V <sub>R</sub>	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	15	- μΑ	
	nateu v <sub>R</sub>	T <sub>A</sub> = 125 °C		19	150		
Typical reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		t <sub>rr</sub>	2400	-	ns	
Typical junction capacitance	4.0 V, 1 MHz		CJ	58	-	pF	

#### Notes

 $^{(1)}$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

 $^{(2)}$  Pulse test: pulse width  $\leq 40 \text{ ms}$ 

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL SE80PWB SE80PWD SE80PWG SE80PWJ UNI				UNIT	
Typical thermal resistance	R <sub>0</sub> JA (1)(2)	60				°C/W
Typical thermal resistance	R <sub>0JM</sub> (3)	2.2				C/ <b>V</b> V

#### **Notes**

- $^{(1)}$  The heat generated must be less than thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$
- $^{(2)}$  Free air, mounted on recommended copper pad area; thermal resistance  $R_{\theta JA}$  junction to ambient
- $^{(3)}$  Mounted on infinite heat sink; thermal resistance  $R_{\theta JM}$  junction-to-mount

IMMUNITY TO ELECTRICAL STATIC DISCHARGE TO THE FOLLOWING STANDARDS ( $T_A = 25~^{\circ}\text{C}$ unless otherwise noted)						
STANDARD TEST TYPE TEST CONDITIONS SYMBOL CLASS V					VALUE	
AEC-Q101-001	Human body model (contact mode)	$C = 100 \text{ pF}, R = 1.5 \text{ k}\Omega$	V <sub>C</sub>	НЗВ	> 8 kV	

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SE80PWJ-M3/I	0.20	I	4500	13" diameter plastic tape and reel		
SE80PWJHM3/I (1)	0.20	I	4500	13" diameter plastic tape and reel		

### Note

(1) AEC-Q101 qualified



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### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

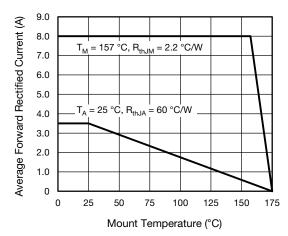


Fig. 1 - Maximum Forward Current Derating Curve

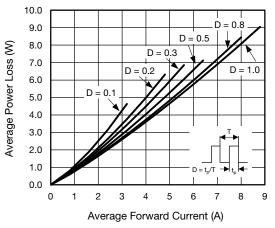


Fig. 2 - Forward Power Loss Characteristics

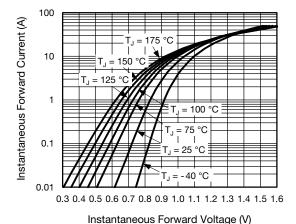


Fig. 3 - Typical Instantaneous Forward Characteristics

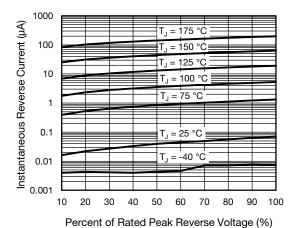


Fig. 4 - Typical Reverse Leakage Characteristics

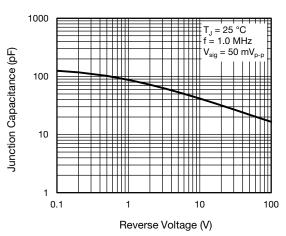


Fig. 5 - Typical Junction Capacitance

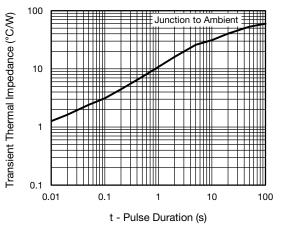


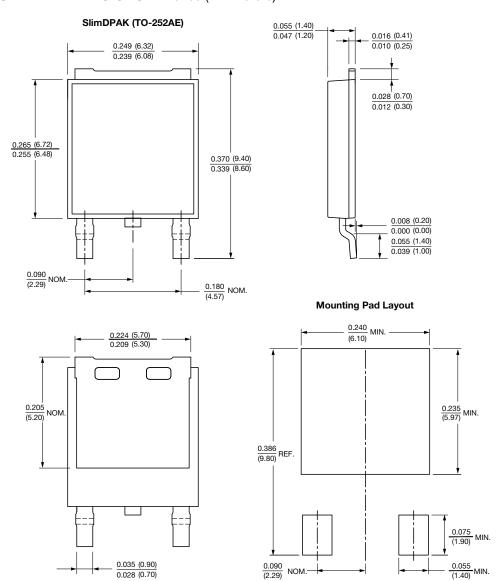
Fig. 6 - Typical Transient Thermal Impedance



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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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